



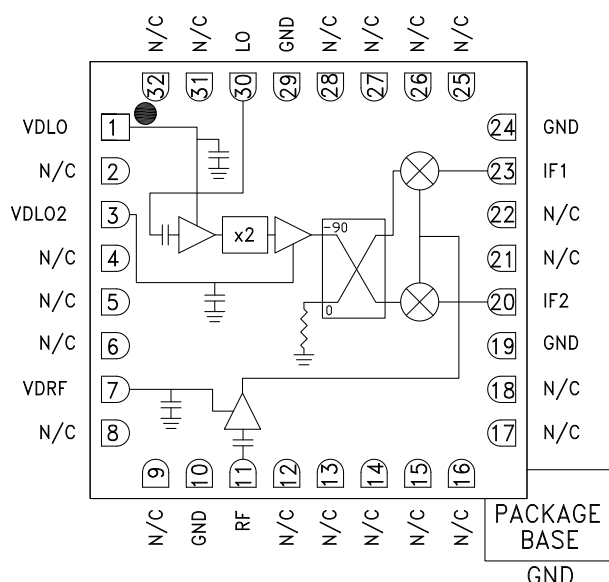
GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

Typical Applications

The HMC904LC5 is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications

Functional Diagram



Features

- Conversion Gain: 12 dB
- Image Rejection: 30 dB
- 2 LO to RF Isolation: 45 dB
- Noise Figure: 3 dB
- Input IP3: 0 dBm
- 32 Lead 5x5mm SMT Package: 25mm²

General Description

The HMC904LC5 is a compact GaAs MMIC I/Q downconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 12 dB with a noise figure of 3 dB and 30 dB of image rejection across the frequency band. The HMC904LC5 utilizes an LNA followed by an image reject mixer which is driven by an active x2 multiplier. The image reject mixer eliminates the need for a filter following the LNA, and removes thermal noise at the image frequency. I and Q mixer outputs are provided and an external 90° hybrid is needed to select the required sideband. The HMC904LC5 is a much smaller alternative to hybrid style image reject mixer downconverter assemblies, and is compatible with surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^\circ\text{C}$, IF = 1000 MHz, LO = +4 dBm, Vdd = 3.5 Vdc USB ^[1]

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF		17 - 20		20 - 24			GHz
Frequency Range, LO		7.5 - 11.75		8.25 - 12.3			GHz
Frequency Range, IF		DC - 3.5		DC - 3.5			GHz
Conversion Gain (As IRM)	8.5	12		8.5	12		dB
Noise Figure		3			3		dB
Image Rejection	20	35		15	30		dB
1 dB Compression (Input)		-8			-6		dBm
2 LO to RF Isolation	40	45		32	40		dB
2 LO to IF Isolation	10	15		15	20		dB
IP3 (Input)		0			0		dBm
Amplitude Balance ^[2]		0.25			0.25		dB
Phase Balance ^[2]		7			7		deg
Total Supply Current		160	190		160	190	mA

[1] Data taken as IRM with external IF 90° Hybrid

[2] Data taken without external 90° hybrid, IF = 500 MHz

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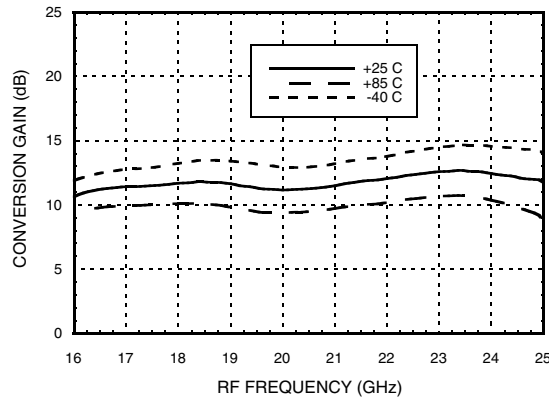
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**GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz**

Data Taken As IRM With External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain USB vs. Temperature



Conversion Gain USB vs. LO Drive

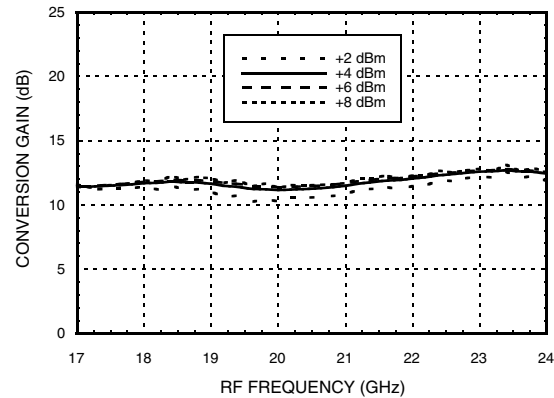
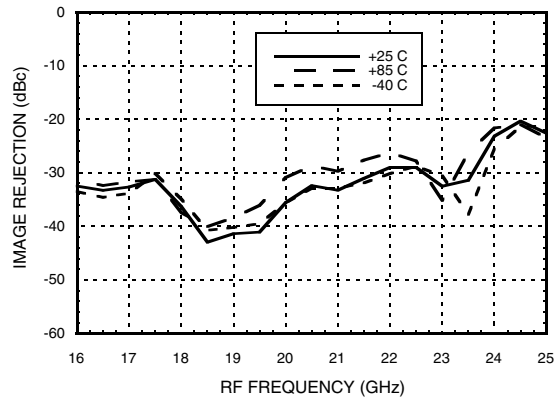
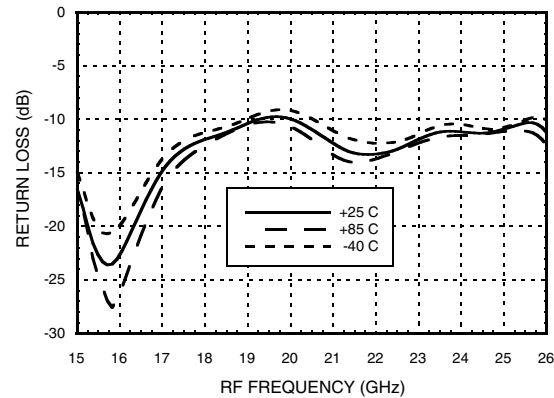


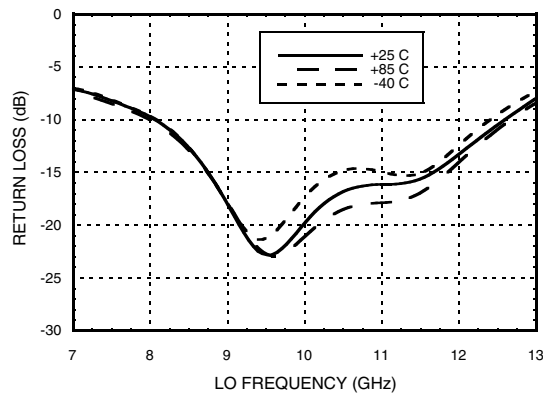
Image Rejection vs. Temperature



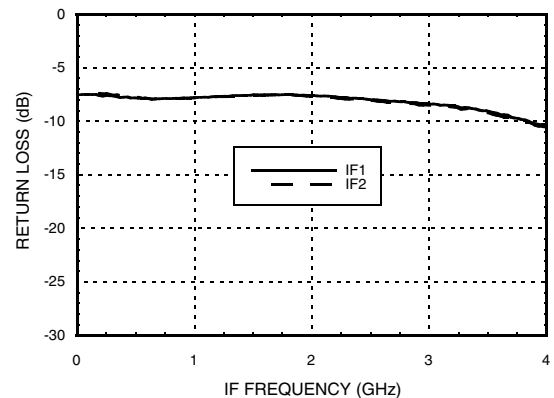
RF Return Loss vs. Temperature



LO Return Loss vs. Temperature



IF Return Loss ^[1]



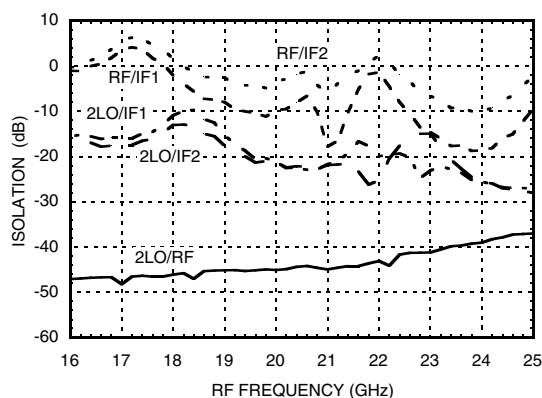
[1] Data taken without external 90° hybrid.



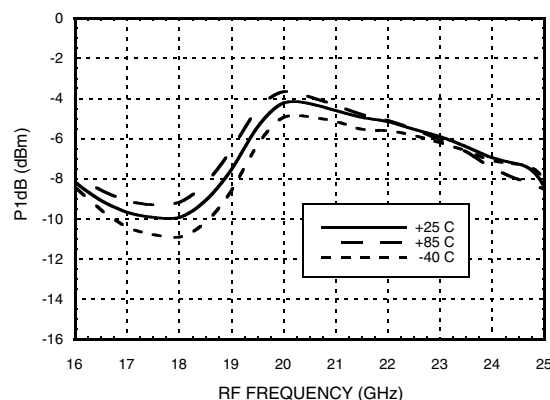
GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

Data Taken as IRM With External IF 90° Hybrid, IF = 1000 MHz

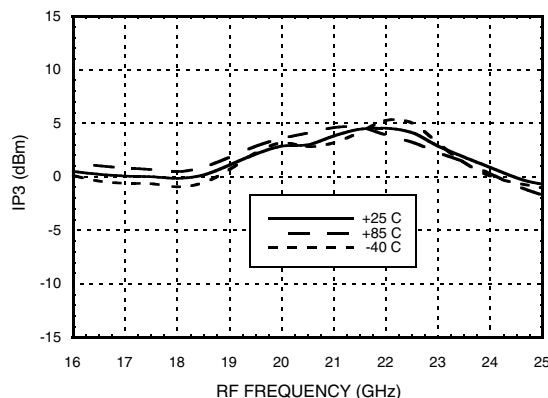
Isolations



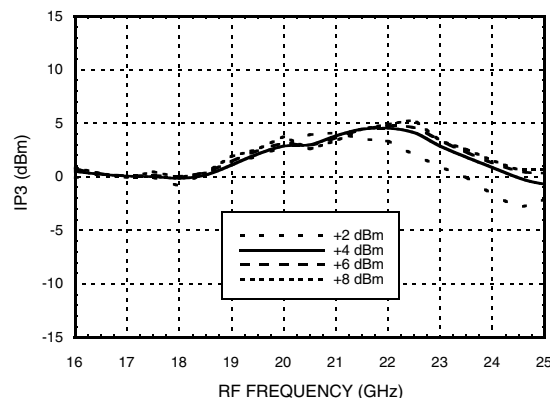
Input P1dB USB vs. Temperature



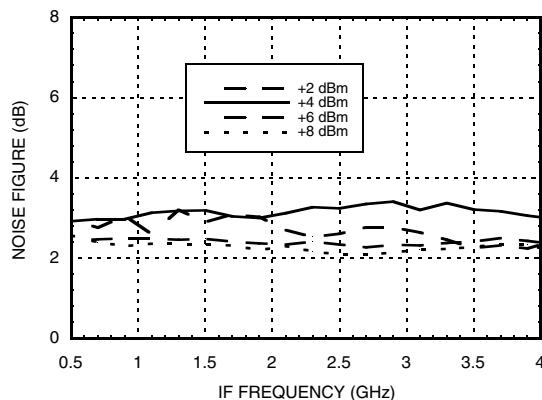
Input IP3, USB vs. Temperature



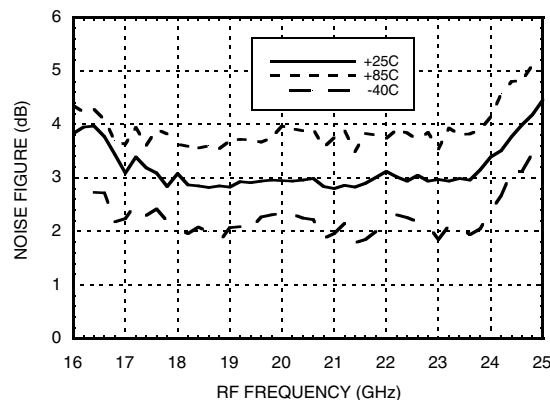
Input IP3, USB vs. LO Drive



Noise Figure vs. LO Drive, LO Frequency = 9 GHz



Noise Figure vs. Temperature, IF Frequency = 1000 MHz



* Conversion gain data taken with external IF 90° IF hybrid, LO frequency fixed at 8.5 GHz and RF varied

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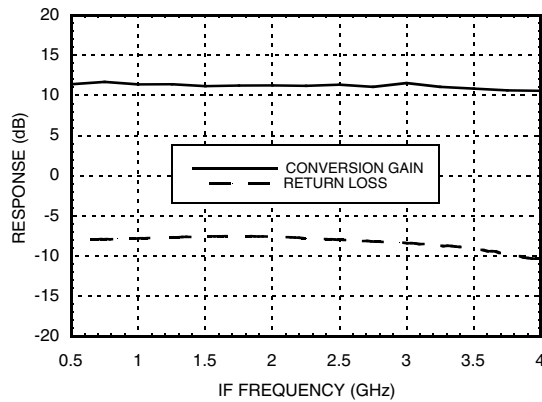
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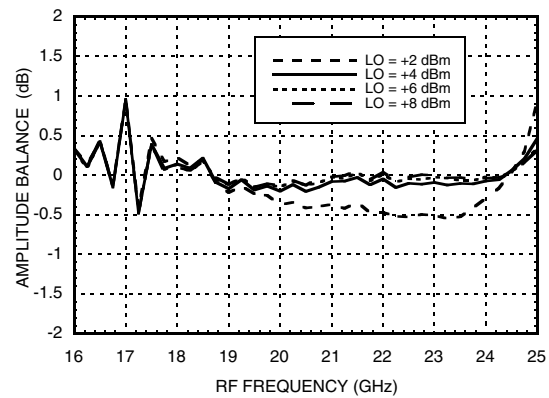
**GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz**

Quadrature Channel Data Taken Without IF 90° Hybrid, IF = 1000 MHz

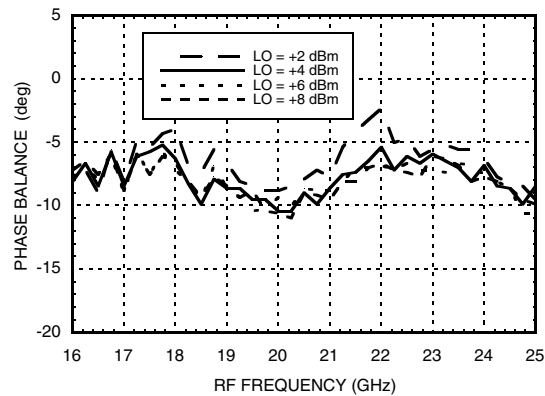
IF Bandwidth



Amplitude Balance vs. LO Drive ^[1]



Phase Balance vs. LO Drive ^[1]



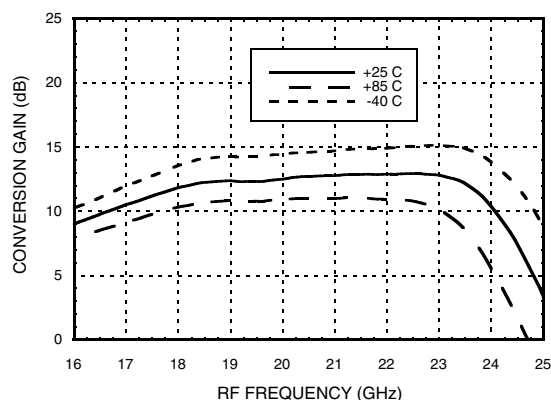
[1] Data taken with IF = 500 MHz



GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

Data Taken as IRM With External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

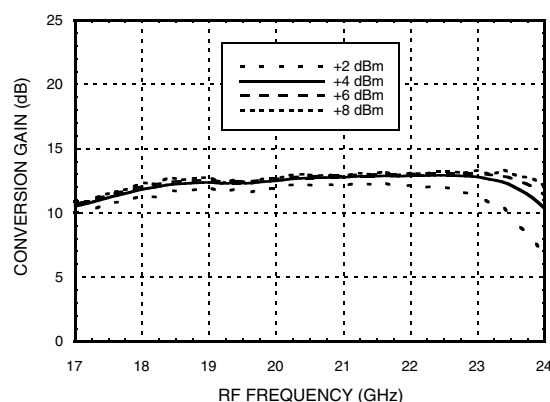
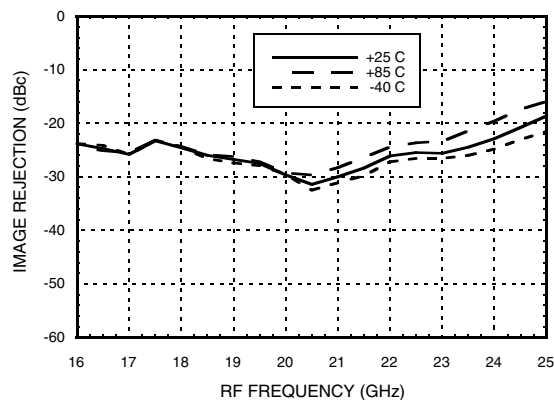
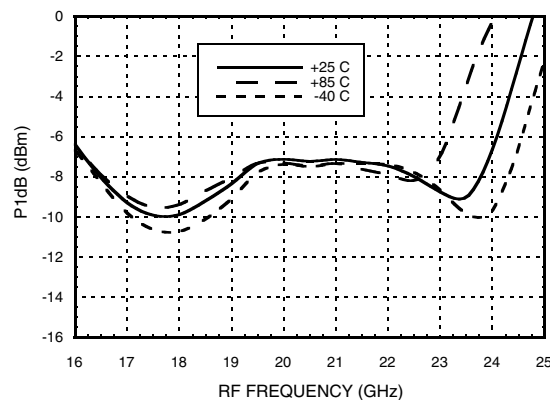


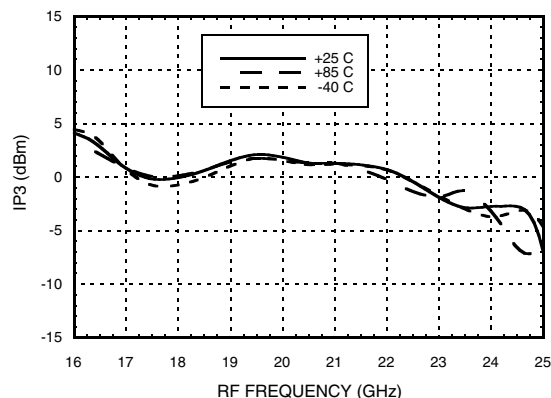
Image Rejection vs. Temperature



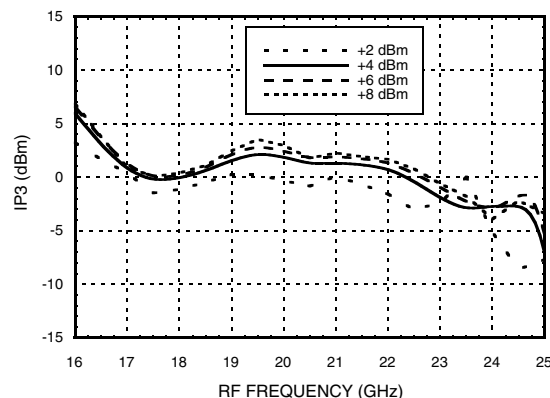
Input P1dB, LSB vs. Temperature



Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive



* Conversion gain data taken with external IF 90° IF hybrid, LO frequency fixed at 8.5 GHz and RF varied

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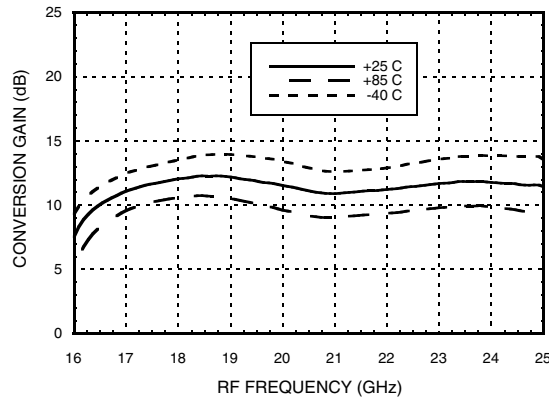
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**GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz**

Data Taken as IRM With External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

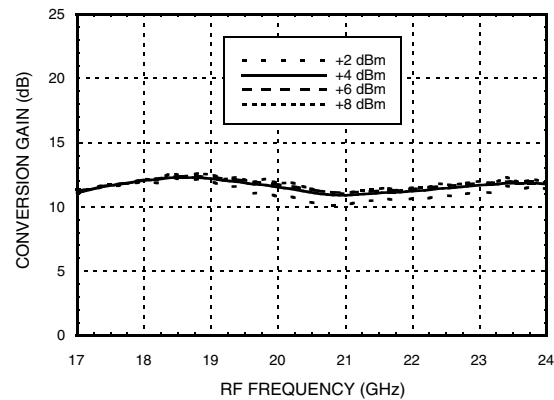
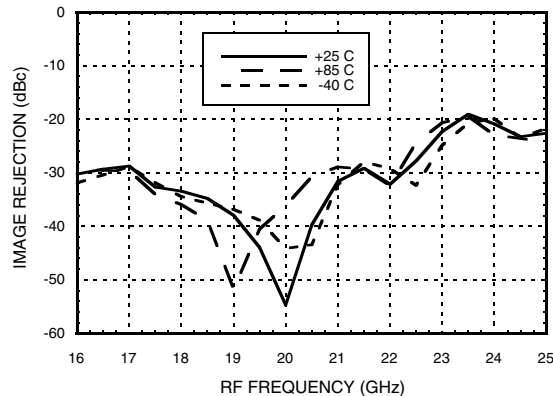
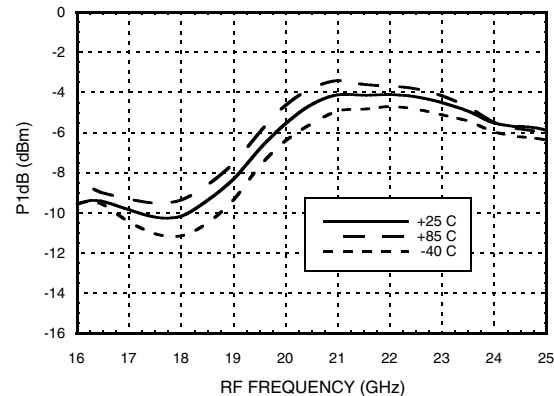


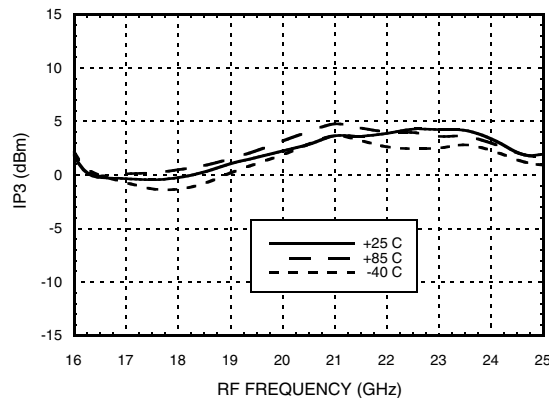
Image Rejection vs. Temperature



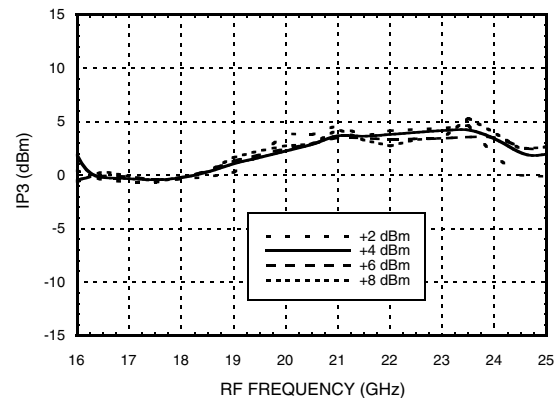
Input P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature



Input IP3, USB vs. LO Drive



* Conversion gain data taken with external IF 90° IF hybrid, LO frequency fixed at 8.5 GHz and RF varied

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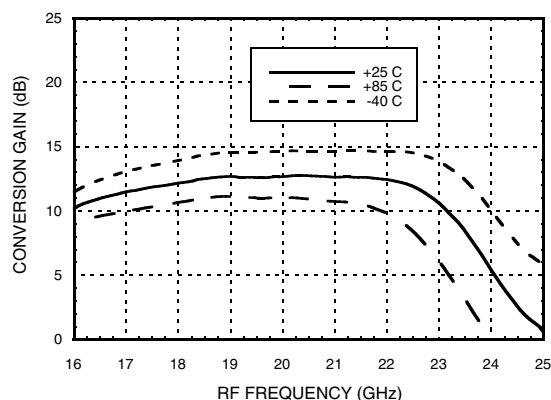
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GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

Data Taken as IRM With External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

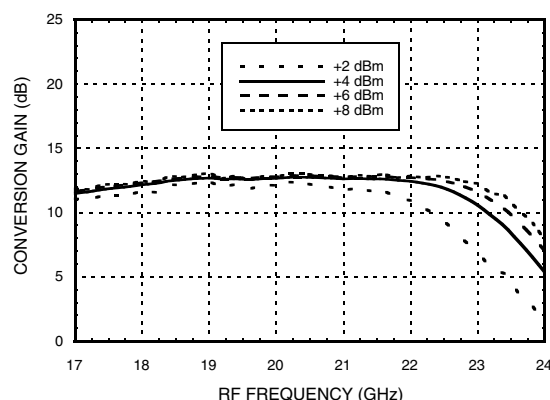
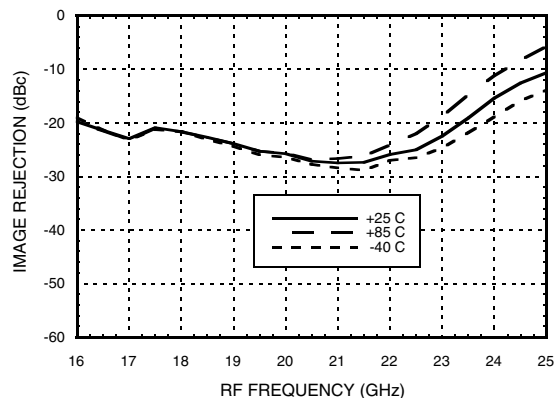
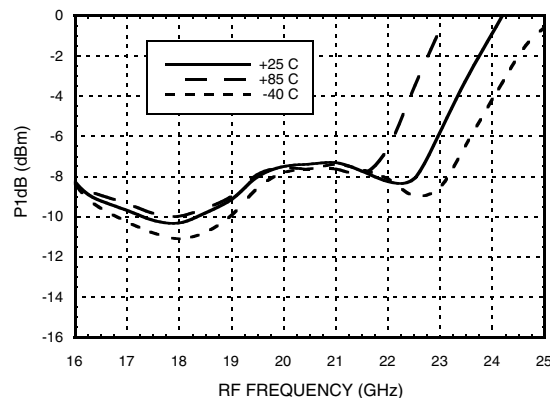


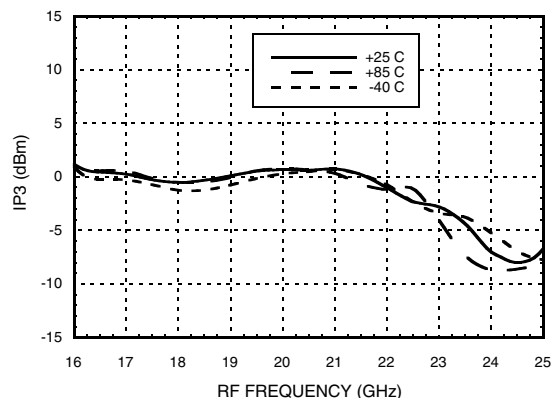
Image Rejection vs. Temperature



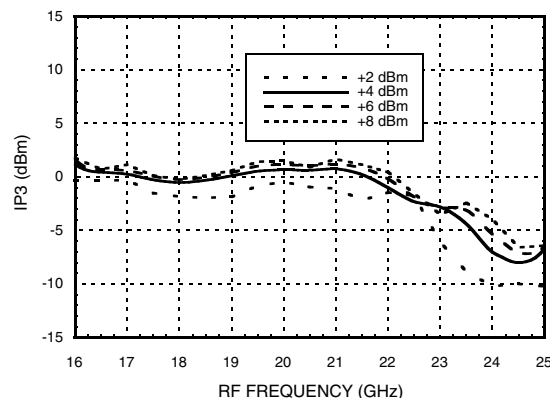
Input P1dB, LSB vs. Temperature



Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive

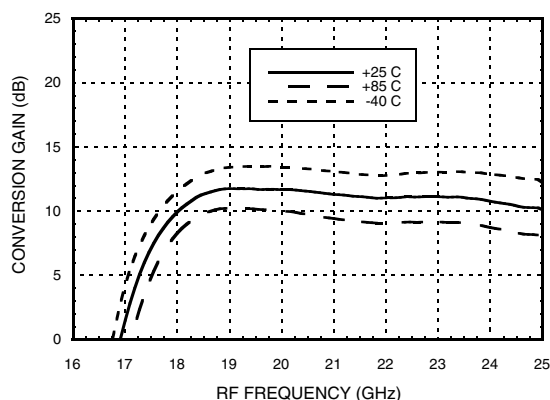




**GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz**

Data Taken as IRM With External IF 90° Hybrid, IF = 3350 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

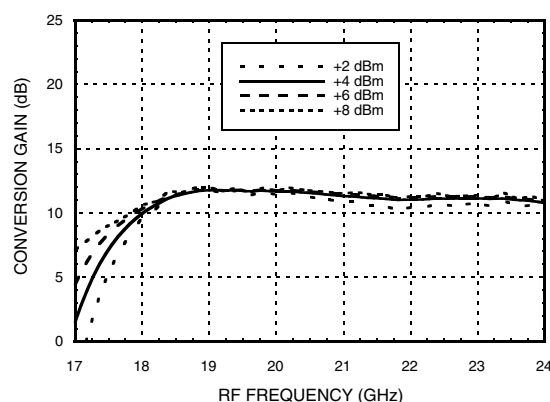
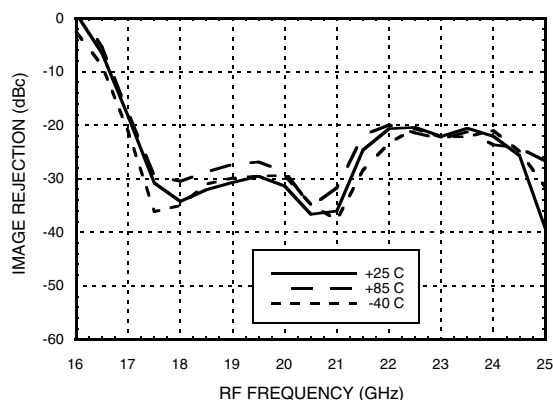
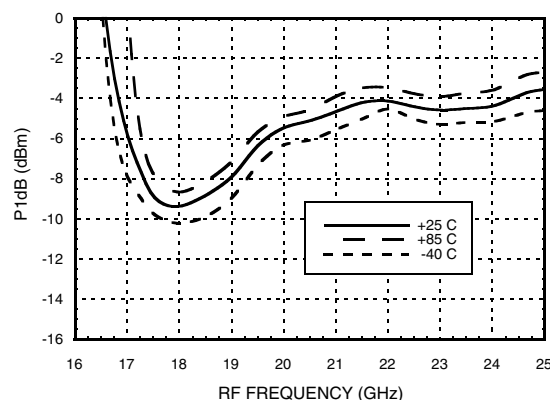


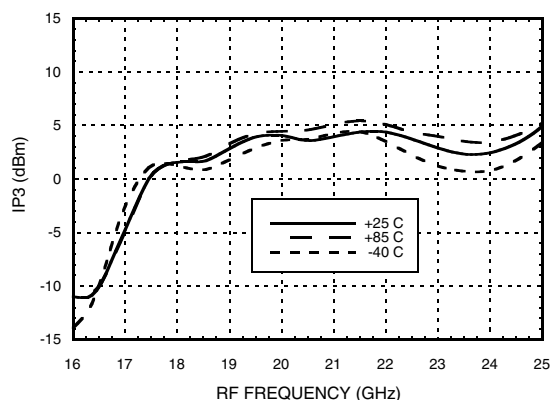
Image Rejection vs. Temperature



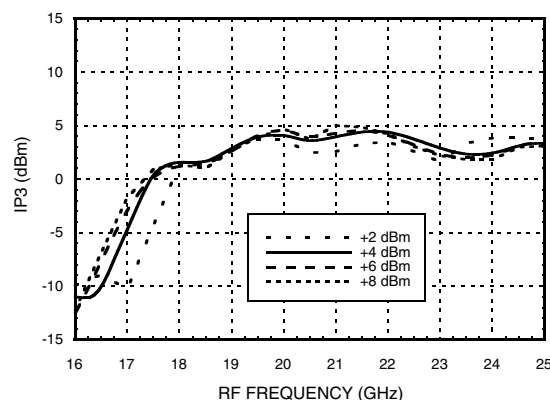
Input P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature



Input IP3, USB vs. LO Drive



* Conversion gain data taken with external IF 90° IF hybrid, LO frequency fixed at 8.5 GHz and RF varied

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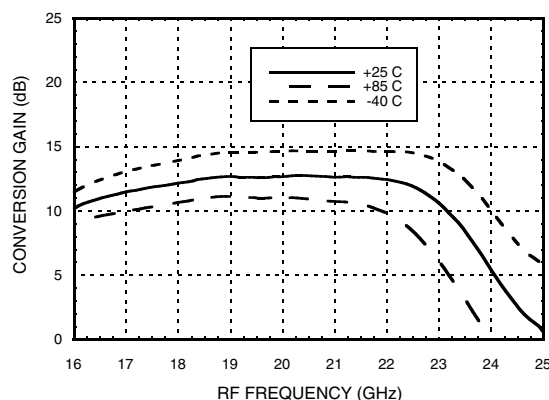
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GaAs MMIC I/Q DOWNCONVERTER 17 - 24 GHz

Data Taken as IRM With External IF 90° Hybrid, IF = 3350 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

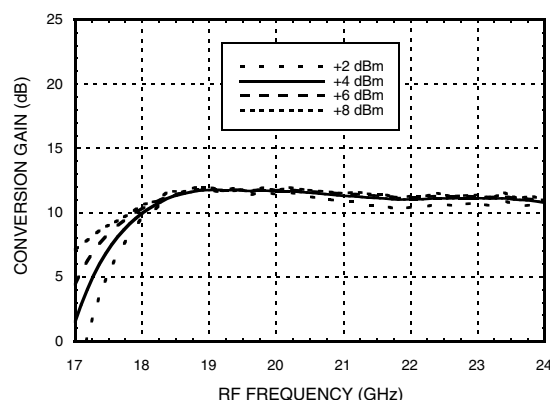
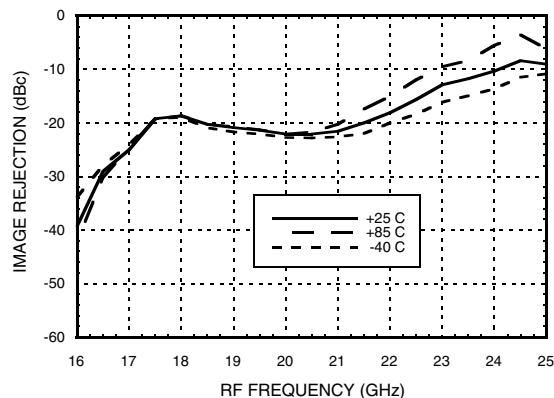
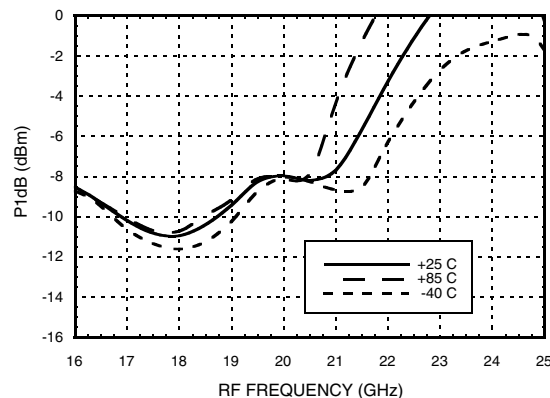


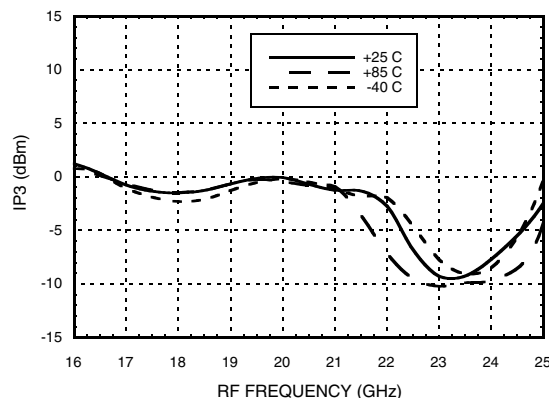
Image Rejection vs. Temperature



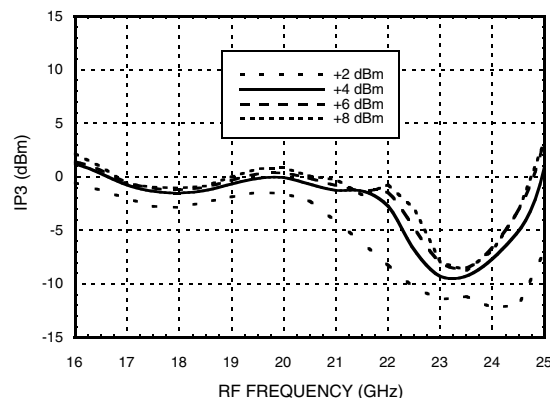
Input P1dB, LSB vs. Temperature



Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive




**GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz**
MxN Spurious Outputs

	nLO				
mRF	0	1	2	3	4
0	-	17	0	23	33
1	8	26	0	23	24
2	68	95	0	66	48
3	xx	xx	xx	xx	xx
4	xx	xx	xx	xx	xx

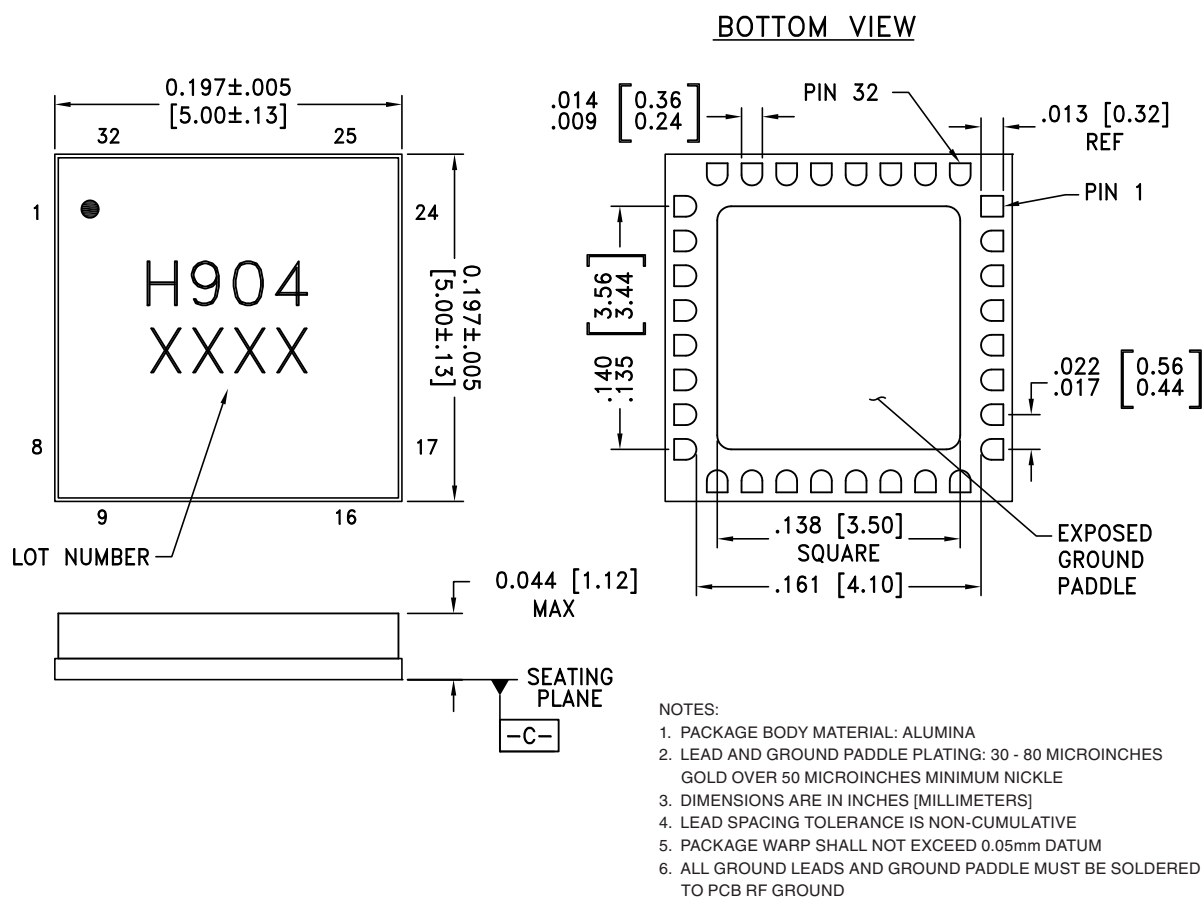
RF = 18 GHz @ -20 dBm
LO = 8.5 GHz @ +4 dBm
Data taken without IF hybrid
All values in dBc below IF power level (1RF -2LO = 1 GHz)

Absolute Maximum Ratings

RF	+2 dBm
LO Drive	+10 dBm
Vdd	5.5V
Channel Temperature	175 °C
Continuous P _{diss} (T=85°C) (derate 18.7 mW/°C above 85°C)	1.69 mW
Thermal Resistance (R _{TH}) (channel to package bottom)	53.2 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C
ESD Sensitivity (HBM)	Class 1B



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

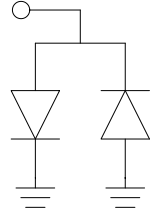
**GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz**
Outline Drawing

Package Information

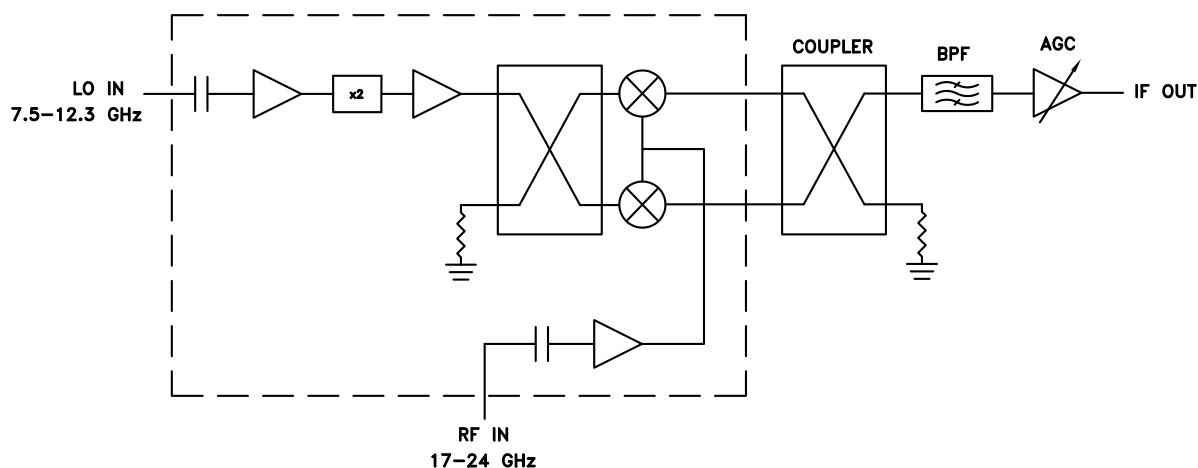
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC904LC5	Alumina, White	Gold over Nickel	MSL3 ^[1]	H904 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX


GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz
Pin Descriptions

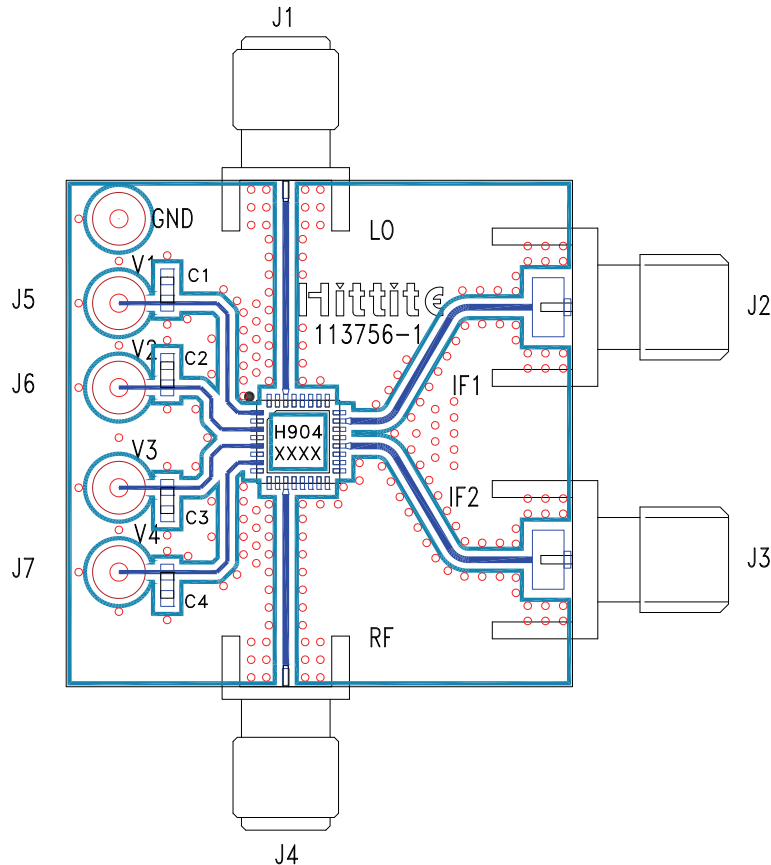
Pin Number	Function	Description	Interface Schematic
1	VDLO	Power supply for first stage of LO amplifier.	VDLO 
2, 4 - 6, 8, 9, 12 - 18, 21, 22, 25 - 28, 31, 32	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	VDLO2	Power supply for second stage of LO amplifier.	VDLO2 
7	VDRF	Power supply for RF LNA.	
10, 19, 24, 29	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	
11	RF	This pin is AC coupled and matched to 50 Ohms	RF 
20	IF2	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary frequency range. For operation to DC, this pin must not sink / source more than 3 mA of current or part non-function and possible failure will result.	IF1, IF2 
23	IF1		
30	LO	This pin is AC coupled and matched to 50 Ohms.	LO 

Typical Application Circuit




**GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz**

Evaluation PCB



List of Materials for Evaluation PCB 113758 [1]

Item	Description
J1, J4	PCB Mount SMA RF Connector, SRI
J2, J3	PCB Mount SMA Connector, Johnson
J5 - J7	DC Pin
C1 - C4	0.01 μ F Capacitor, 0603 Pkg.
U1	HMC904LC5
PCB [2]	113756 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

**GaAs MMIC I/Q DOWNCONVERTER
17 - 24 GHz**



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- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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